

**NPN PRE-BIASED SMALL SIGNAL DUAL SURFACE MOUNT TRANSISTOR**
**Features**

- Epitaxial Planar Die Construction
- Complementary PNP Types Available (DDA)
- Built-In Biasing Resistors
- "Lead Free", RoHS Compliant (Note 1)
- Halogen and Antimony Free "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

Part Number	R1 (NOM)	R2 (NOM)
DDC124EU	22K $\Omega$	22K $\Omega$
DDC144EU	47K $\Omega$	47K $\Omega$
DDC114YU	10K $\Omega$	47K $\Omega$
DDC123JU	2.2K $\Omega$	47K $\Omega$
DDC114EU	10K $\Omega$	10K $\Omega$

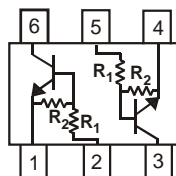
**Mechanical Data**

- Case: SOT363
- Case material: Molded Plastic. "Green" Molding Compound.
- Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish
- Weight: 0.006 grams (approximate)

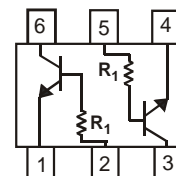
Part Number	R1 Only
DDC113TU	1K $\Omega$
DDC143TU	4.7K $\Omega$
DDC114TU	10K $\Omega$



Top View



R1, R2



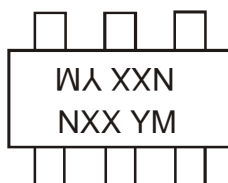
R1 Only

Device Schematic

**Ordering Information** (Note 3 & 4)

Product	Grade	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DDC124EU-7-F	Commercial	N17	7	8	3,000
DDC124EUQ-7-F	Automotive	N17	7	8	3,000
DDC124EUQ-13-F	Automotive	N17	13	8	10,000
DDC144EU-7-F	Commercial	N20	7	8	3,000
DDC114YU-7-F	Commercial	N14	7	8	3,000
DDC114YUQ-7-F	Automotive	N14	7	8	3,000
DDC123JU-7-F	Commercial	N06	7	8	3,000
DDC114EU-7-F	Commercial	N13	7	8	3,000
DDC114EUQ-7-F	Automotive	N13	7	8	3,000
DDC114EUQ-13-F	Automotive	N13	13	8	10,000
DDC113TU-7-F	Commercial	N01	7	8	3,000
DDC143TU-7-F	Commercial	N07	7	8	3,000
DDC114TU-7-F	Commercial	N12	7	8	3,000
DDC114TUQ-7-F	Automotive	N12	7	8	3,000

- Notes:
1. No purposefully added lead.
  2. Diodes Inc's "Green" policy can be found on our website at <http://www.diodes.com>.
  3. For packaging details, go to our website at <http://www.diodes.com>.
  4. Products with Q-suffix are automotive grade. Automotive products are electrical and thermal the same as the commercial, except where specified.

**Marking Information**


NXX = Product Type Marking Code  
 See Page 1 Diagrams  
 YM = Date Code Marking  
 Y = Year (ex: T = 2006)  
 M = Month (ex: 9 = September)

## Date Code Key

Year	2010	2011	2012	2013	2014	2015	2016	2017
Code	X	Y	Z	A	B	C	D	E

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

**Maximum Ratings** @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit
Supply Voltage		V <sub>CC</sub>	50	V
Input Voltage	DDC124EU	V <sub>IN</sub>	-10 to +40	V
	DDC144EU		-10 to +40	
	DDC114YU		-6 to +40	
	DDC123JU		-5 to +12	
	DDC114EU		-10 to +40	
	DDC113TU		-5V max	
	DDC143TU		-5V max	
DDC114TU	-5V max			
Output Current		I <sub>C(MAX)</sub>	100	mA

**Thermal Characteristics** @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P <sub>D</sub>	150	mW
Thermal Resistance, Junction to Ambient Air (Note 5)	R <sub>θJA</sub>	833	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

Notes: 5. Mounted on FR4 PC Board with minimum recommended pad layout

**Electrical Characteristics** @T<sub>A</sub> = 25°C unless otherwise specified

**For R1 only devices: DDC113TU & DDC143TU & DDC114TU**

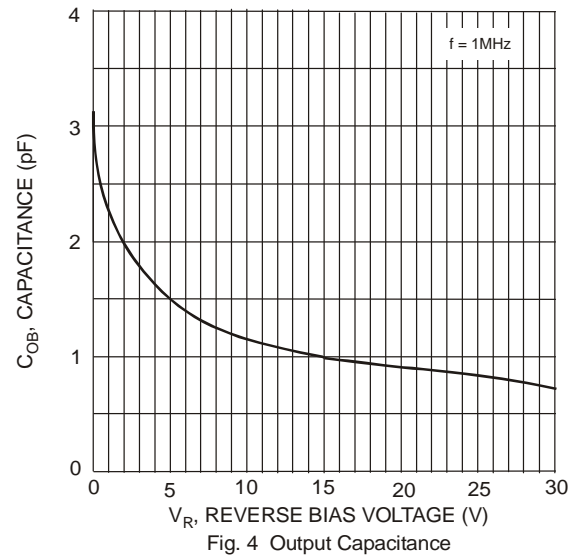
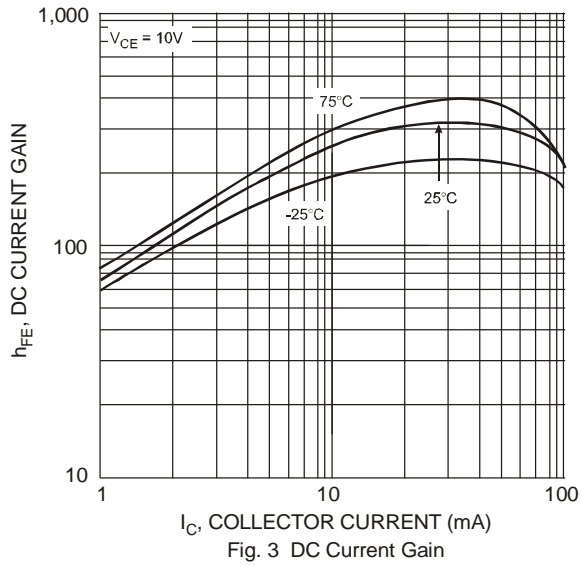
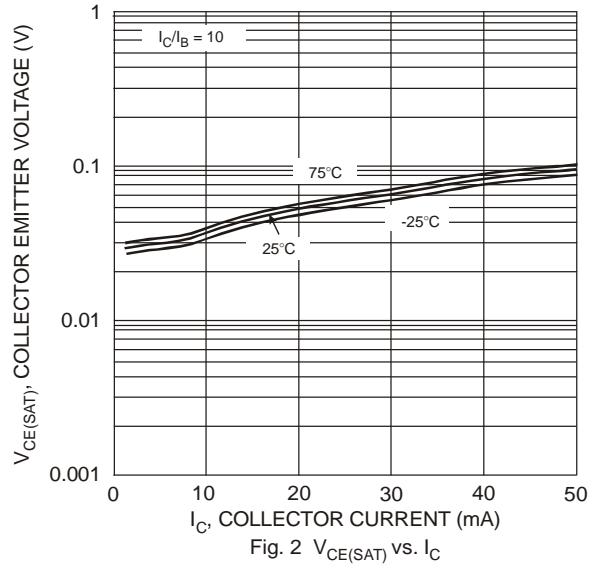
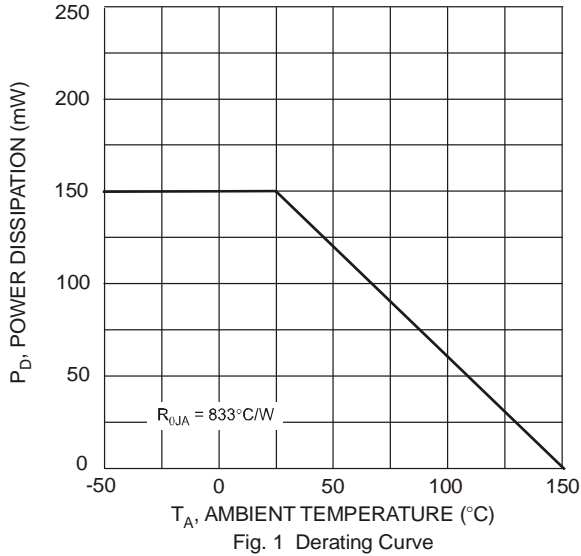
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	50	—	—	V	I <sub>C</sub> = 50μA
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	50	—	—	V	I <sub>C</sub> = 1mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	5	—	—	V	I <sub>E</sub> = 50μA
Collector Cutoff Current	I <sub>CBO</sub>	—	—	0.5	μA	V <sub>CB</sub> = 50V
Emitter Cutoff Current	I <sub>EBO</sub>	—	—	0.5	μA	V <sub>EB</sub> = 4V
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	—	—	0.3	V	I <sub>C</sub> /I <sub>B</sub> = 2.5mA / 0.25mA DDC143TU I <sub>C</sub> /I <sub>B</sub> = 1mA / 0.1mA DDC114TU I <sub>C</sub> /I <sub>B</sub> = 10mA / 1mA DDC113TU
DC Current Transfer Ratio	h <sub>FE</sub>	100	250	600	—	I <sub>C</sub> = 1mA, V <sub>CE</sub> = 5V
Input Resistor (R <sub>1</sub> ) Tolerance	ΔR <sub>1</sub>	-30	—	+30	%	—
Gain-Bandwidth Product (Note 6)	f <sub>T</sub>	—	250	—	MHz	V <sub>CE</sub> = 10V, I <sub>E</sub> = -5mA, f = 100MHz

**For R1, R2 devices: DDC124EU & DDC144EU & DDC114YU & DDC123JU & DDC114EU**

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Input Voltage	V <sub>I(off)</sub>	0.5	1.1	—	V	V <sub>CC</sub> = 5V, I <sub>O</sub> = 100μA
		0.5	1.1	—		
Input Voltage	V <sub>I(on)</sub>	0.3	—	—	V	V <sub>O</sub> = 0.3, I <sub>O</sub> = 5mA V <sub>O</sub> = 0.3, I <sub>O</sub> = 2mA V <sub>O</sub> = 0.3, I <sub>O</sub> = 1mA V <sub>O</sub> = 0.3, I <sub>O</sub> = 5mA V <sub>O</sub> = 0.3, I <sub>O</sub> = 10mA
		0.5	—	—		
		0.5	1.9	3.0		
		—	1.9	3.0		
		—	1.4	1.1		
Output Voltage	V <sub>O(on)</sub>	—	0.1	0.3	V	I <sub>O</sub> /I <sub>I</sub> = 10mA / 0.5mA I <sub>O</sub> /I <sub>I</sub> = 10mA / 0.5mA I <sub>O</sub> /I <sub>I</sub> = 5mA / 0.25mA I <sub>O</sub> /I <sub>I</sub> = 5mA / 0.25mA I <sub>O</sub> /I <sub>I</sub> = 10mA / 0.5mA
		—	—	—		
		—	—	—		
		—	—	—		
		—	—	—		
Input Current	I <sub>I</sub>	—	—	0.36	mA	V <sub>I</sub> = 5V
		—	—	0.18		
		—	—	0.88		
		—	—	3.6		
		—	—	0.88		
Output Current	I <sub>O(off)</sub>	—	—	0.5	μA	V <sub>CC</sub> = 50V, V <sub>I</sub> = 0V
DC Current Gain	G <sub>I</sub>	56	—	—	—	V <sub>O</sub> = 5V, I <sub>O</sub> = 5mA V <sub>O</sub> = 5V, I <sub>O</sub> = 5mA V <sub>O</sub> = 5V, I <sub>O</sub> = 10mA V <sub>O</sub> = 5V, I <sub>O</sub> = 5mA V <sub>O</sub> = 5V, I <sub>O</sub> = 10mA V <sub>O</sub> = 5V, I <sub>O</sub> = 5mA
		68	—	—		
		68	—	—		
		80	—	—		
		80	—	—		
		30	—	—		
Input Resistor (R <sub>1</sub> ) Tolerance	ΔR <sub>1</sub>	-30	—	+30	%	—
Resistance Ratio Tolerance	R <sub>2</sub> /R <sub>1</sub>	-20	—	+20	%	—
Gain-Bandwidth Product (Note 6)	f <sub>T</sub>	—	250	—	MHz	V <sub>CE</sub> = 10V, I <sub>E</sub> = 5mA, f = 100MHz

Notes: 6. Transistor - For Reference Only

**Typical Curves – DDC123JU One Section**



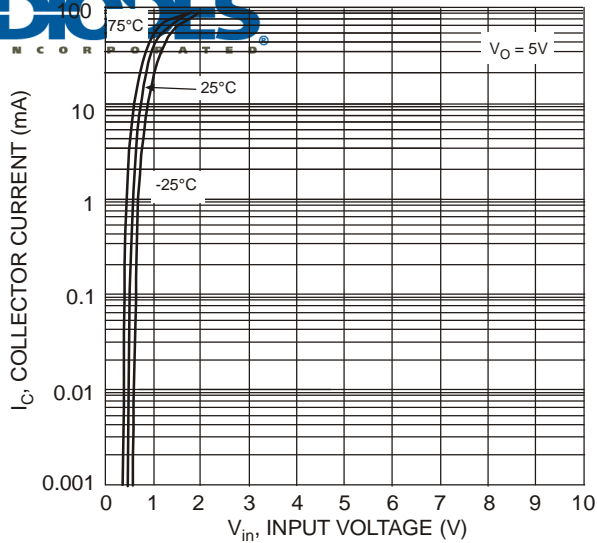


Fig. 5 Collector Current vs. Input Voltage

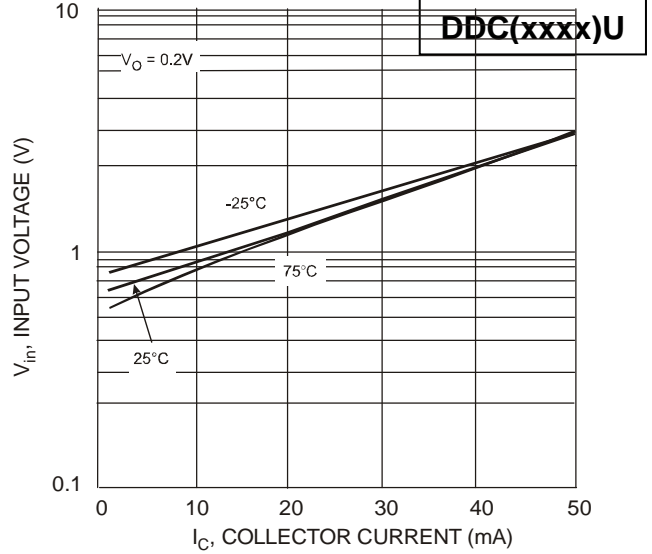


Fig. 6 Input Voltage vs. Collector Current

**Typical Curves – DDC114YU One Section**

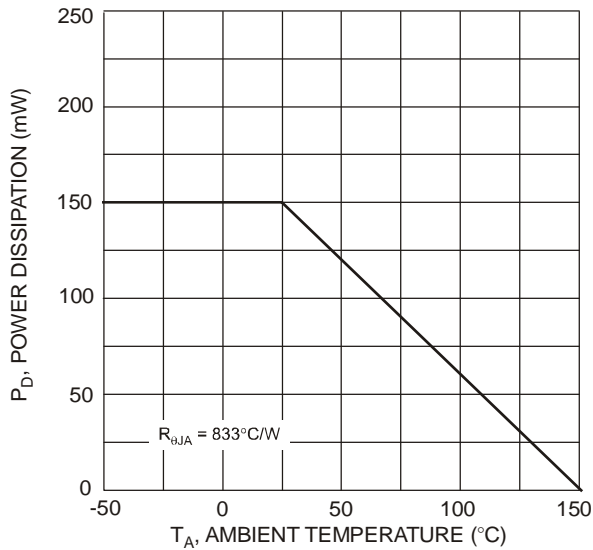


Fig. 1 Derating Curve

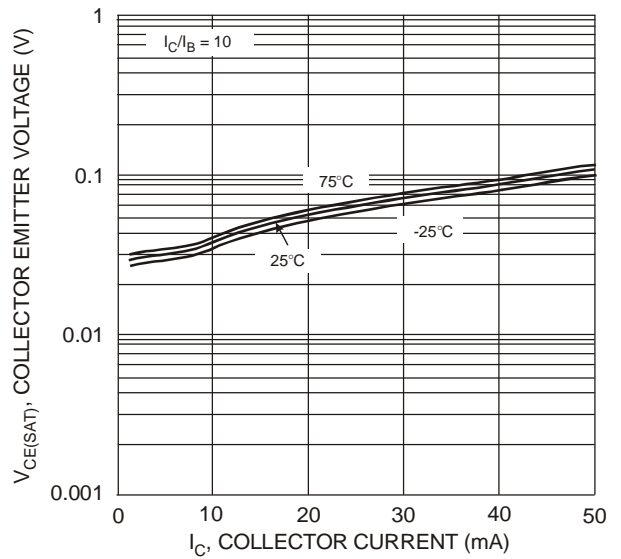


Fig. 2  $V_{CE(SAT)}$  vs.  $I_C$

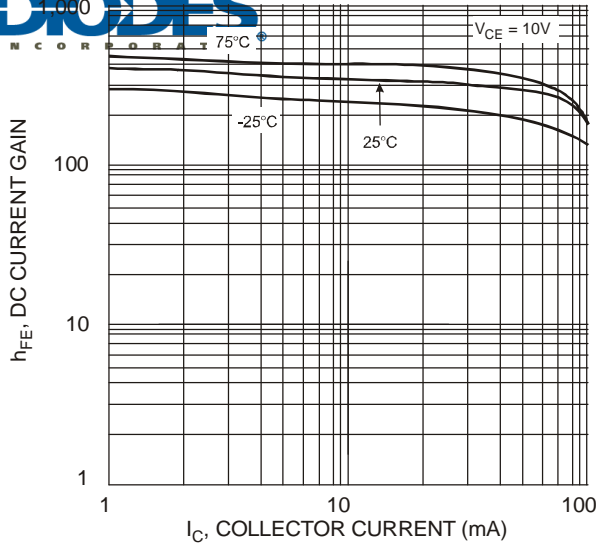


Fig. 3 DC Current Gain

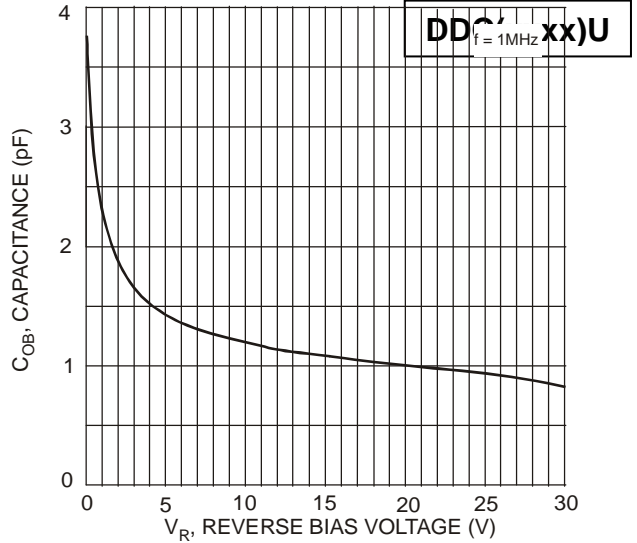


Fig. 4 Output Capacitance

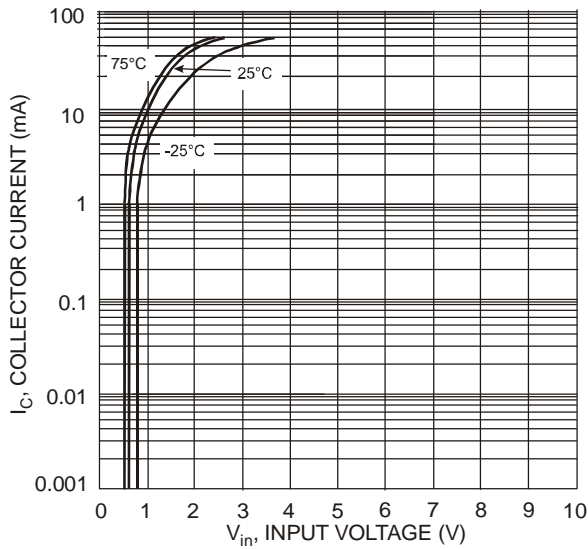


Fig. 5 Collector Current vs. Input Voltage

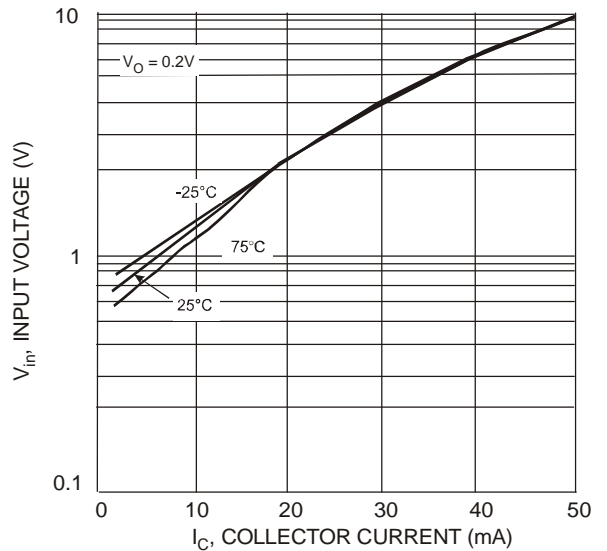


Fig. 6 Input Voltage vs. Collector Current

**Typical Curves – DDC124EU One Section**

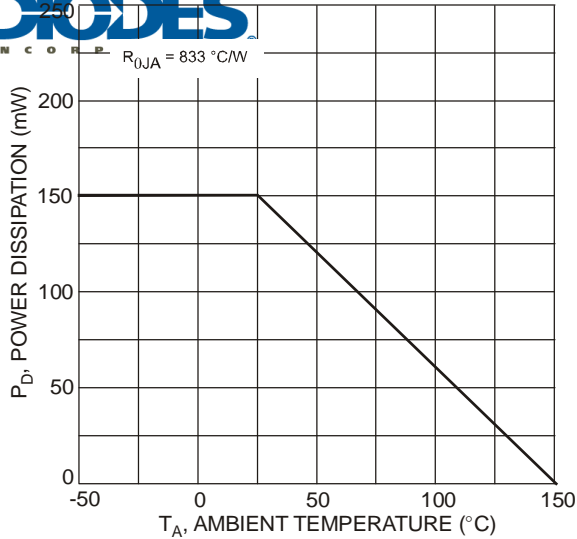


Fig. 1 Power Dissipation vs. Ambient Temperature

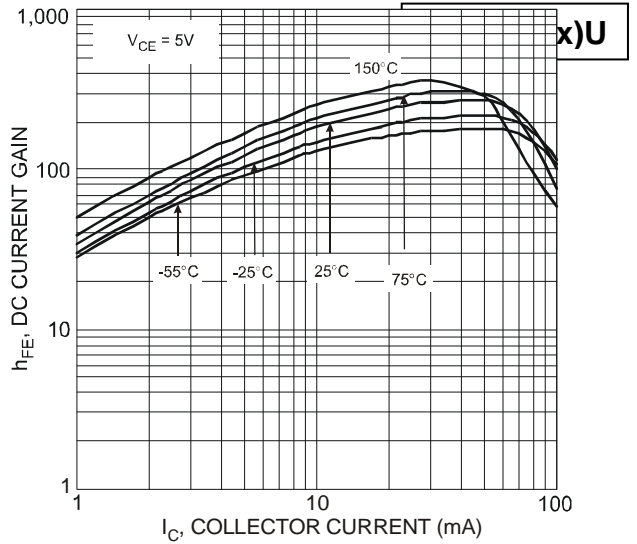


Fig. 2 Typical DC Current Gain vs. Collector Current

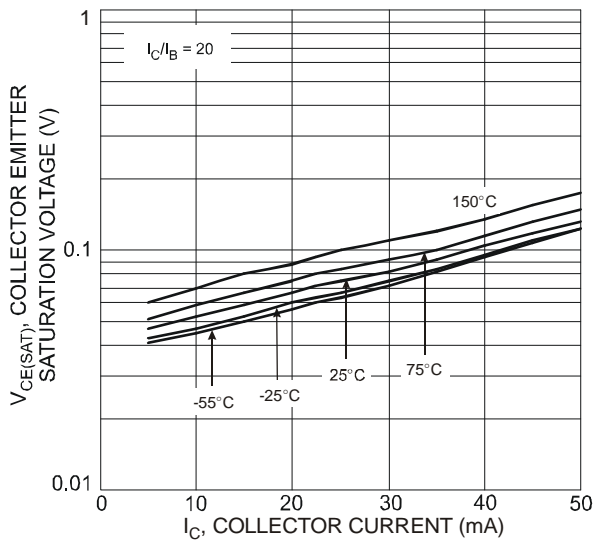


Fig. 3 Collector Emitter Saturation Voltage vs. Collector Current

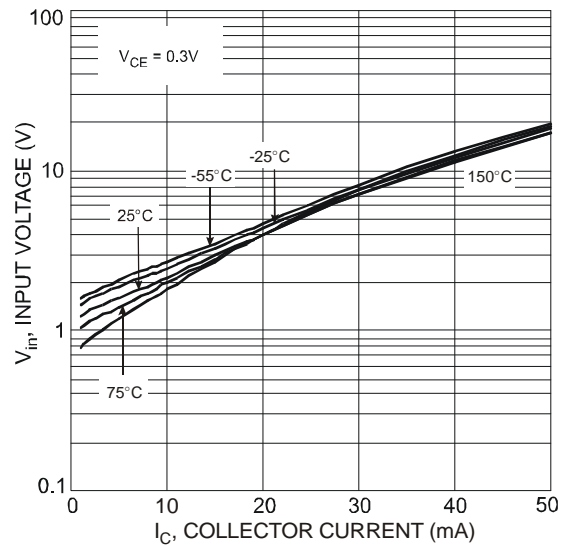
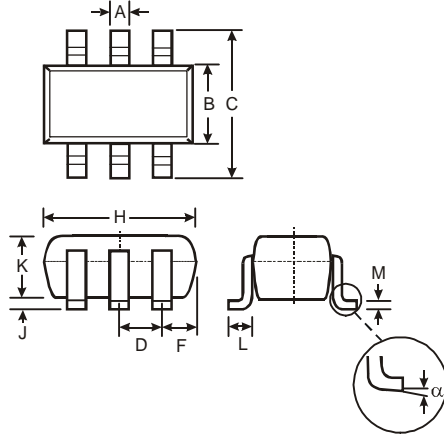


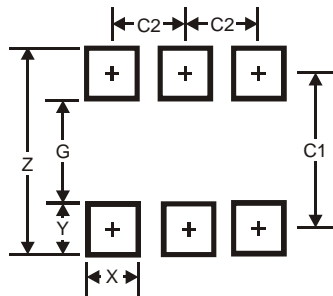
Fig. 4 Input Voltage vs. Collector Current

**Package Outline Dimensions**



SOT363		
Dim	Min	Max
A	0.10	0.30
B	1.15	1.35
C	2.00	2.20
D	0.65 Typ	
F	0.40	0.45
H	1.80	2.20
J	0	0.10
K	0.90	1.00
L	0.25	0.40
M	0.10	0.22
α	0°	8°
All Dimensions in mm		

**Suggested Pad Layout**



Dimensions	Value (in mm)
Z	2.5
G	1.3
X	0.42
Y	0.6
C1	1.9
C2	0.65



**IMPORTANT NOTICE**

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

**LIFE SUPPORT**

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
  - 1. are intended to implant into the body, or
  - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2011, Diodes Incorporated

[www.diodes.com](http://www.diodes.com)

Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибьюторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

Мы предлагаем:

- Конкурентоспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



Тел: +7 (812) 336 43 04 (многоканальный)  
Email: [org@lifeelectronics.ru](mailto:org@lifeelectronics.ru)